IXYS UK WESTCODE

Date:- 10 Aug, 2016

Data Sheet Issue:- 2

Insulated Gate Bi-Polar Transistor

Type T1800GB45A

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{CES}	Collector – emitter voltage	4500	V
$V_{DC\ link}$	Permanent DC voltage for 100 FIT failure rate.	2800	V
V_{GES}	Peak gate – emitter voltage	±20	V

	RATINGS	MAXIMUM LIMITS	UNITS
I_C	DC collector current, IGBT	1800	A
I_{CRM}	Repetitive peak collector current, t_p=1ms, IGBT	3600	A
$I_{F(DC)}$	Continuous DC forward current, Diode	1800	A
I_{FRM}	Repetitive peak forward current, t_p=1ms, Diode	3600	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{RM}=60%V_{RRM}, Diode (Note 4)	38.6	kA
I_{FSM2}	Peak non-repetitive surge t_p=10ms, V_{RM}≤10V, Diode (Note 4)	42.5	kA
P_{MAX}	Maximum power dissipation, IGBT (Note 2)	13.7	kW
$(di/dt)_{cr}$	Critical diode di/dt (note 3)	3500	A/µs
T_j	Operating temperature range.	-40 to +125	°C
T_{stg}	Storage temperature range.	-40 to +125	°C

Notes: -
1) Unless otherwise indicated T_j = 125ºC.
2) T_{sink} = 25°C, double side cooled.
3) Maximum commutation loop inductance 200nH.
4) Half-sinewave, 125°C T_j initial.

Characteristics

IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_{CE(sat)}$	Collector – emitter saturation voltage	-	2.8	3.2	I_C = 1800A, V_{GE} = 15V, T_j = 25°C	V
		-	3.6	4.0	I_C = 1800A, V_{GE} = 15V	V
V_{T0}	Threshold voltage	-	-	1.82	Current range: 600A – 1800A	V
r_T	Slope resistance	-	-	1.21		mΩ
$V_{GE(TH)}$	Gate threshold voltage	-	5.1	-	V_{CE} = V_{GE}, I_C = 180mA	V
I_{CES}	Collector – emitter cut-off current		45	70	V_{CE} = V_{CES}, V_{GE} = 0V	mA
I_{GES}	Gate leakage current	-	-	±20	V_{GE} = ±20V	µA
C_{ies}	Input capacitance	-	280	-	V_{CE} = 25V, V_{GE} = 0V, f = 1MHz	nF
$t_{d(on)}$	Turn-on delay time	-	1.5	-		µs
$t_r(V)$	Rise time	-	3.3	-	I_C =1800A, V_{CE} =2800V, di/dt=3000A/µs	µs
$Q_{g(on)}$	Turn-on gate charge	-	12.5	-	V_{GE} = ±15V, L_s=200nH	µC
E_{on}	Turn-on energy	-	11	-	$R_{g(ON)}$= 3Ω, $R_{g(OFF)}$=11Ω, C_{GE}=183nF	J
$t_{d(off)}$	Turn-off delay time	-	4.7	-	Integral diode used as freewheel diode	µs
$t_f(I)$	Fall time	-	2.5	-	(Note 3 & 4)	µs
$Q_{g(off)}$	Turn-off gate charge	-	10	-		µC
E_{off}	Turn-off energy	-	10.5	-		J
I_{SC}	Short circuit current	-	5500	-	V_{GE}=+15V, V_{CC}=2800V, V_{CEmax}≤V_{CES}, t_p≤10µs	A

Diode Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
V_F	Forward voltage	-	3.7	4.0	I_F = 1800A, T_j =25°C	V
		-	3.9	4.2	I_F = 1800A	V
V_{To}	Threshold voltage	-	-	2.27	Current range 600A - 1800A	V
r_T	Slope resistance	-	-	1.07		mΩ
I_{rm}	Peak reverse recovery current	-	1600	-		A
Q_{rr}	Recovered charge	-	2000	-	I_F = 1800A, V_r = 2800V, V_{GE} = -15V,	µC
t_{rr}	Reverse recovery time, 50% chord	-	1.6	-	di/dt=3000A/µs	µs
E_r	Reverse recovery energy	-	2.8	-		J

Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
R_{thJK}	Thermal resistance junction to sink, IGBT	-	-	7.3	Double side cooled	K/kW
		-	-	11.9	Collector side cooled	K/kW
		-	-	19	Emitter side cooled	K/kW
R_{thJK}	Thermal resistance junction to sink, Diode	-	-	14.4	Double side cooled	K/kW
		-	-	22.3	Cathode side cooled	K/kW
		-	-	41.1	Anode side cooled	K/kW
F	Mounting force	50	-	70	Note 2	kN
W_t	Weight	-	2	-		kg

Notes:-
1) Unless otherwise indicated T_j=125°C.
2) Consult application note 2008AN01 for detailed mounting requirements
3) C_{GE} is additional gate – emitter capacitance added to output of gate drive
4) Figures 6 to 9 are obtained using integral diode as freewheeling diode

Curves

Figure 1 – Typical collector-emitter saturation voltage characteristics

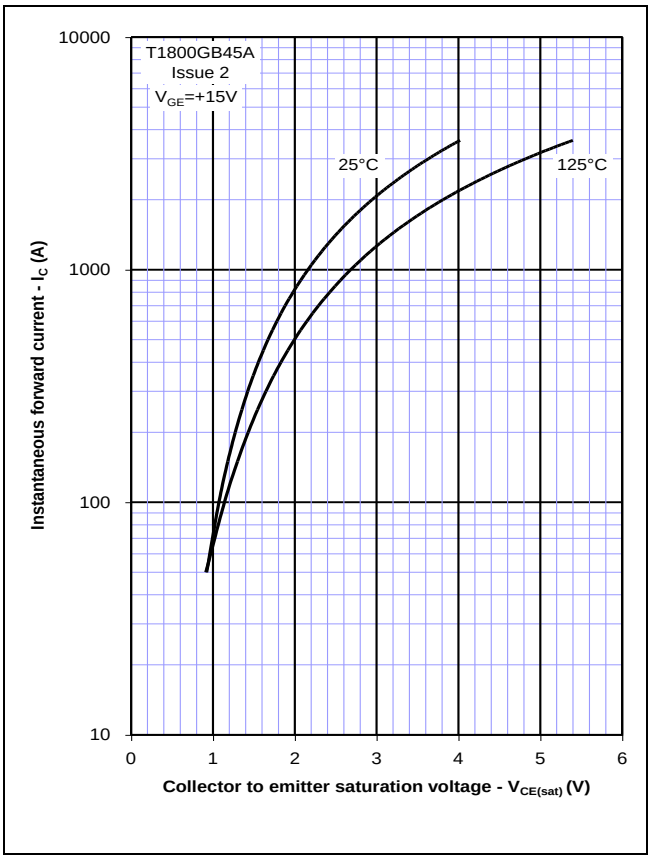


Figure 2 – Typical output characteristic

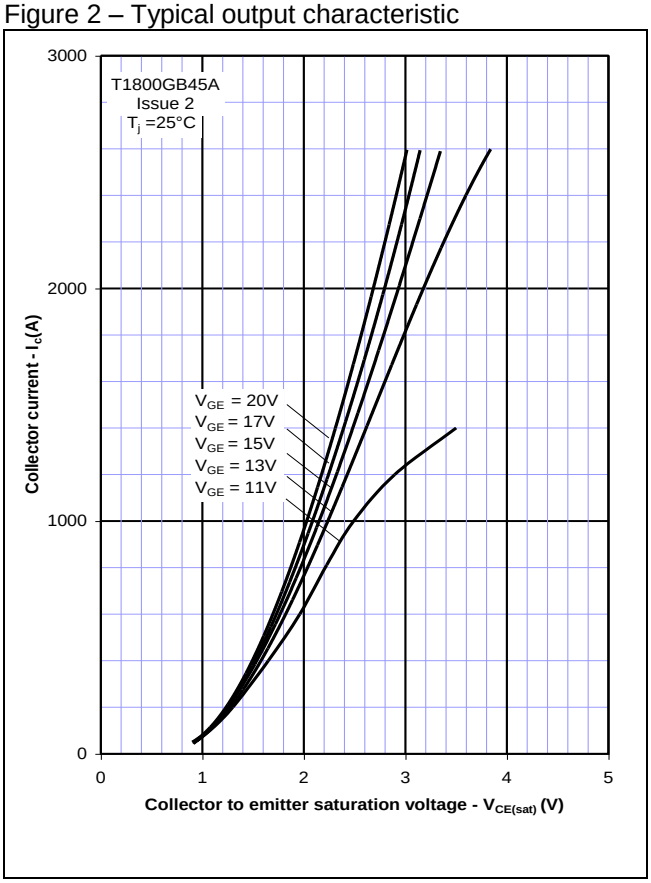


Figure 3 – Typical output characteristic

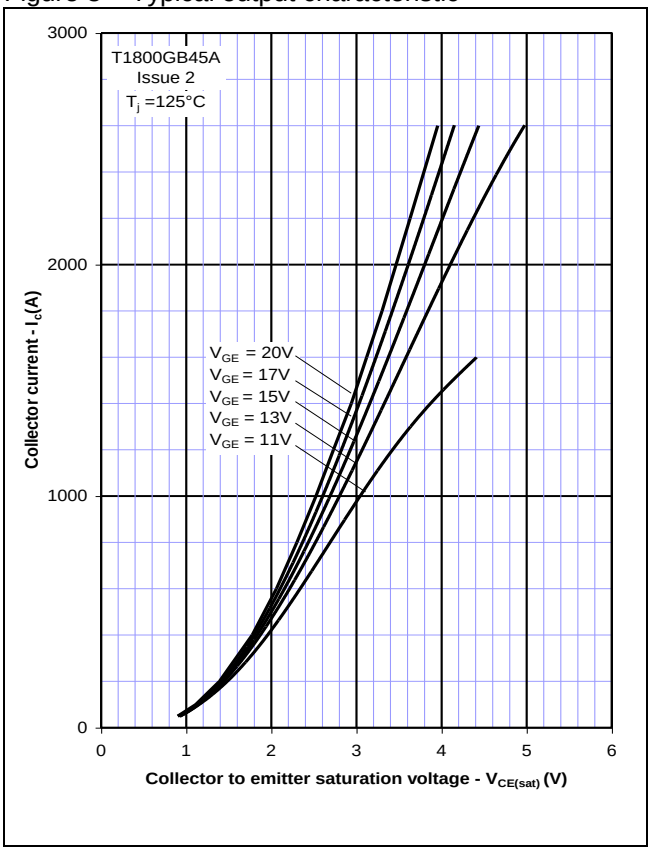


Figure 4 – Typical turn-on delay time vs gate resistance

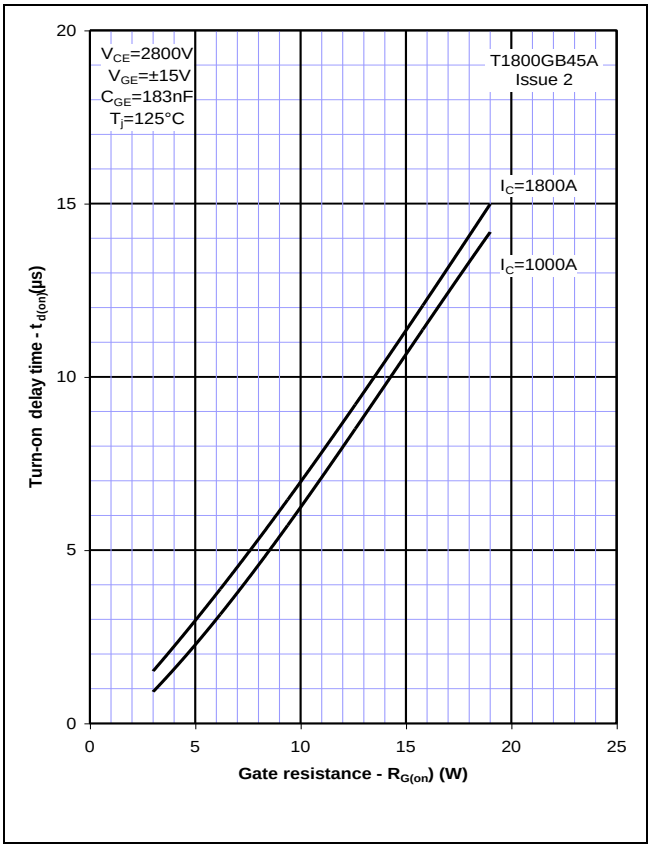


Figure 5 – Typical turn-off delay time vs. gate resistance

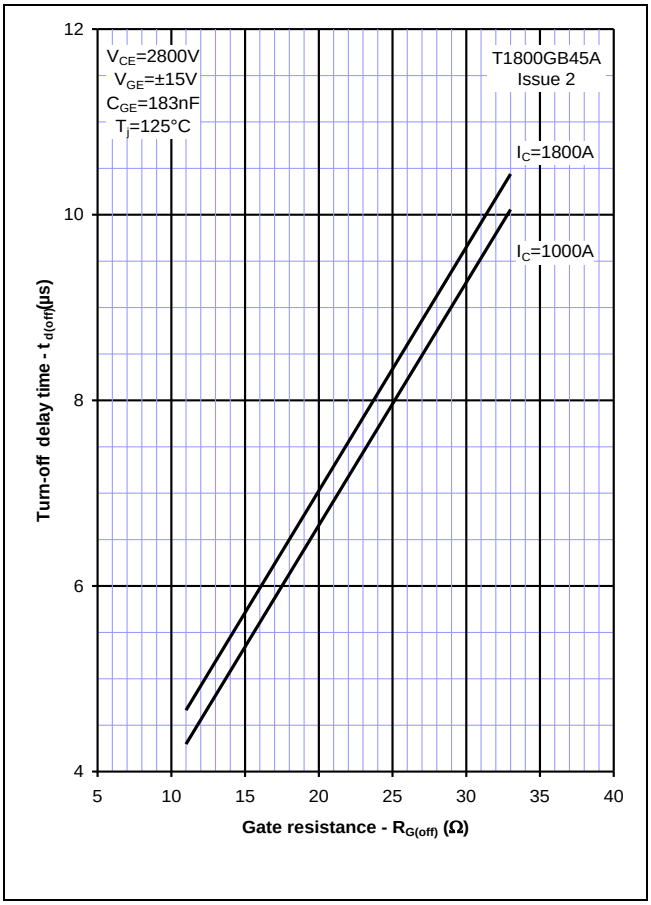


Figure 6 – Typical turn-on energy vs. collector current

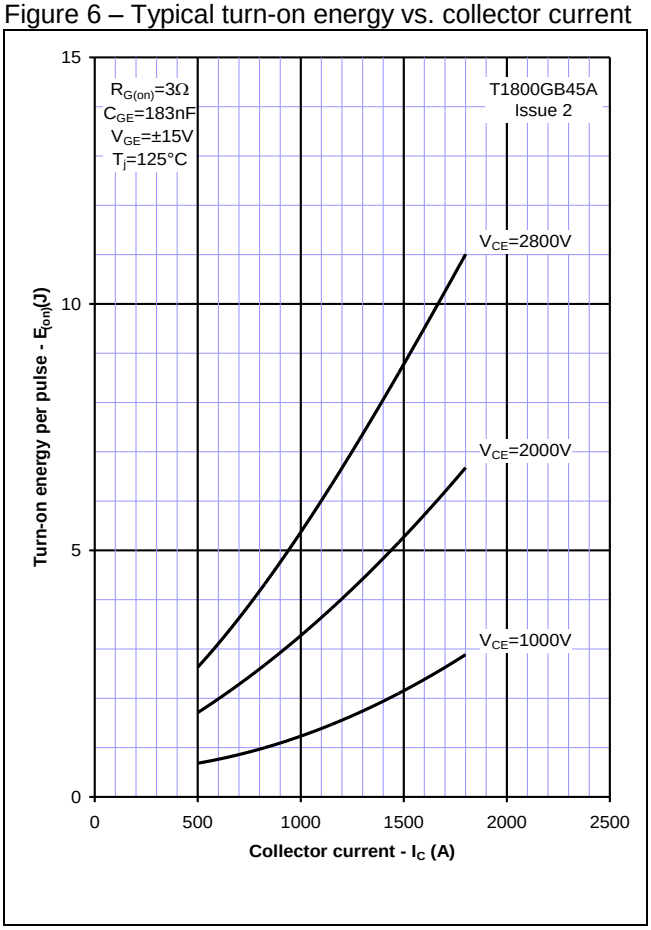


Figure 7 – Typical turn-on energy vs. di/dt

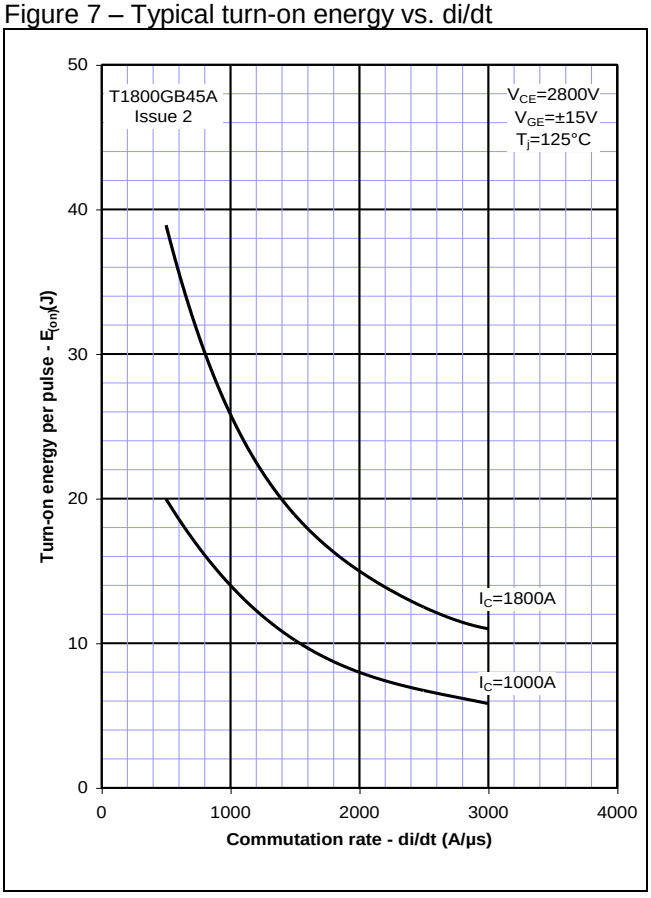


Figure 8 – Typical turn-off energy vs. collector current

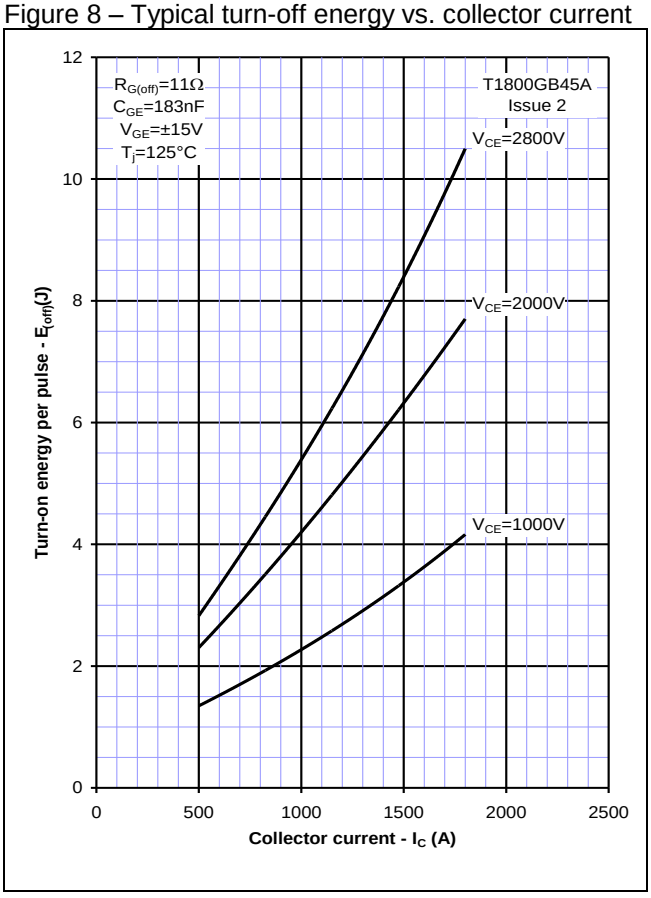


Figure 9 – Turn-off energy vs voltage

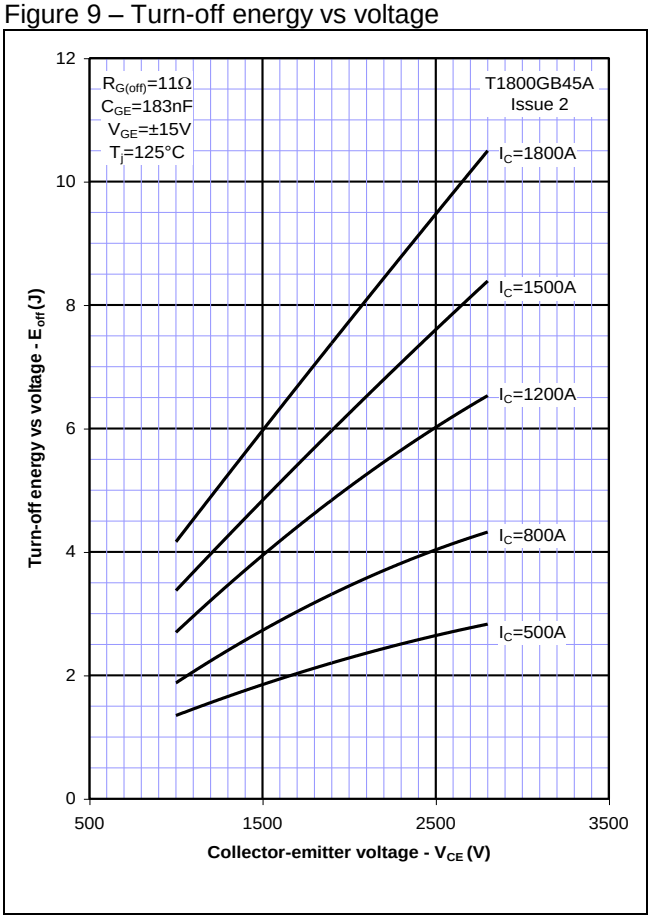


Figure 10 – Safe operating area (IGBT)

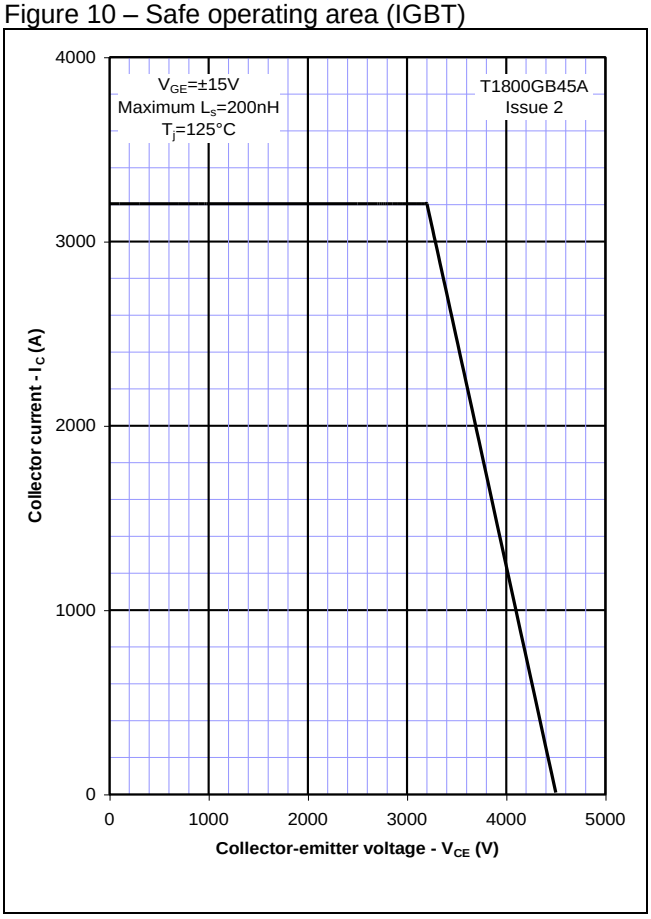


Figure 11 – Typical diode forward characteristics

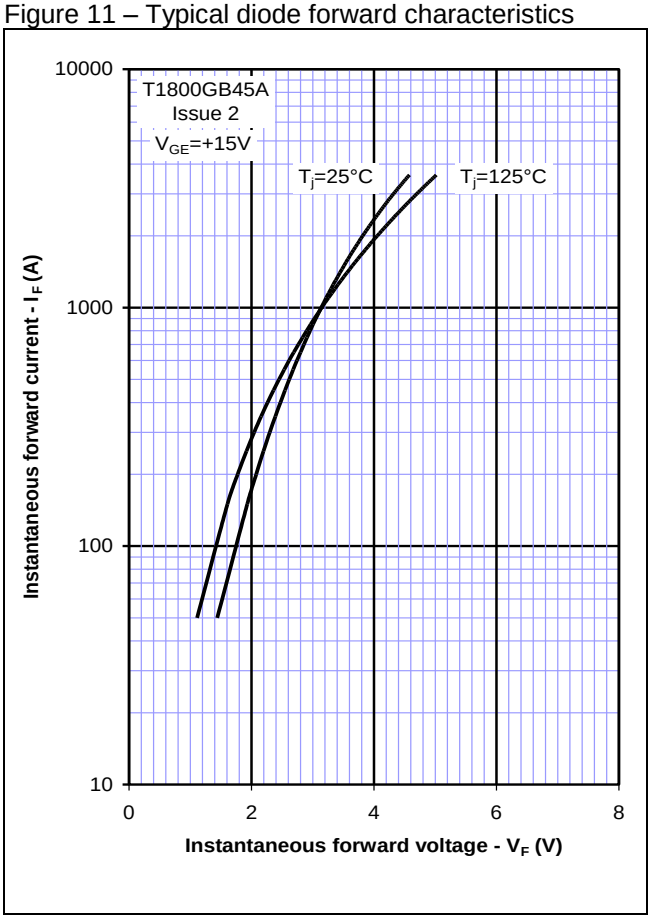


Figure 12 – Typical recovered charge

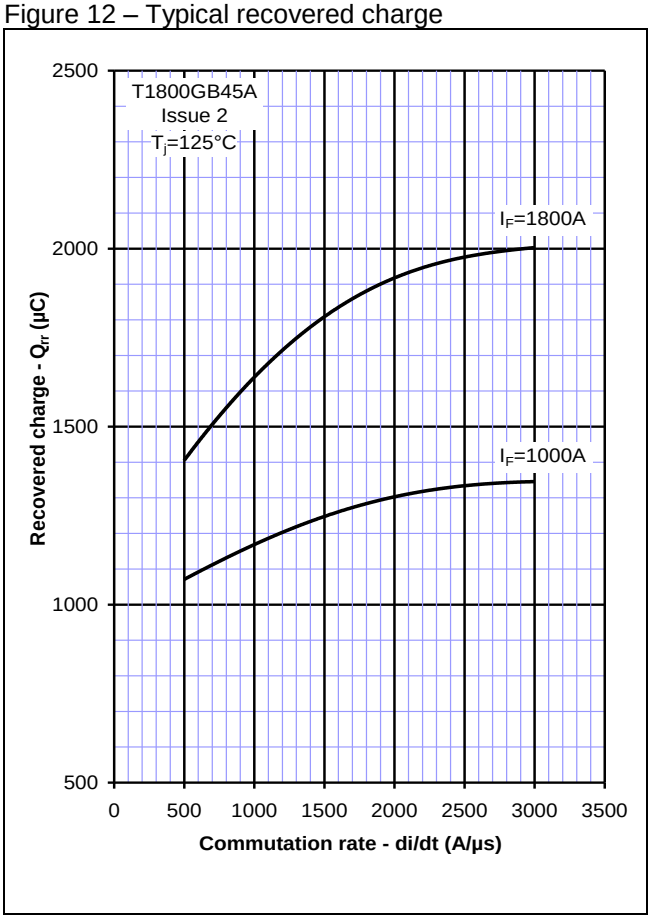


Figure 13 – Typical reverse recovery current

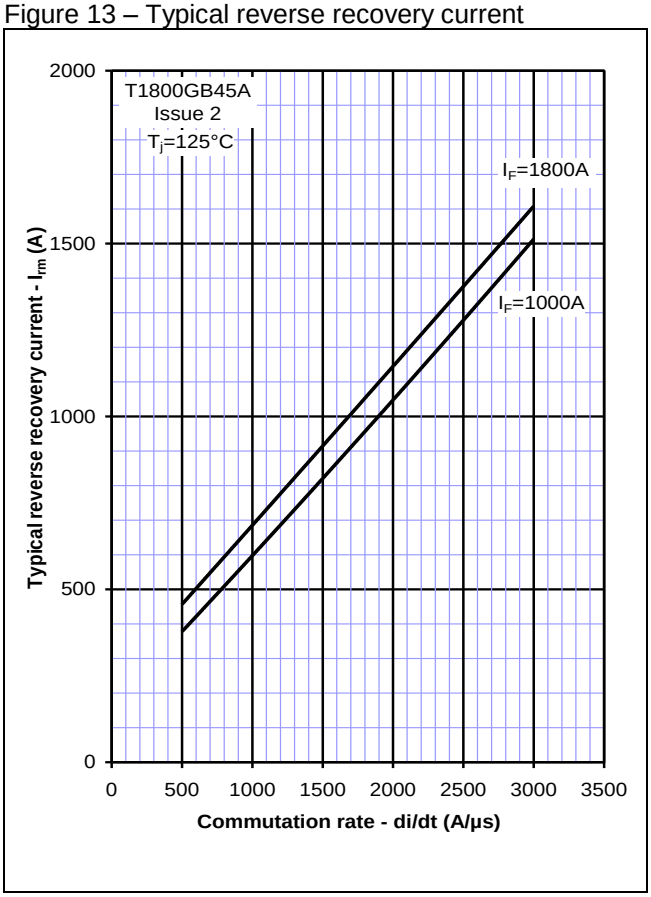


Figure 14 – Typical reverse recovery time

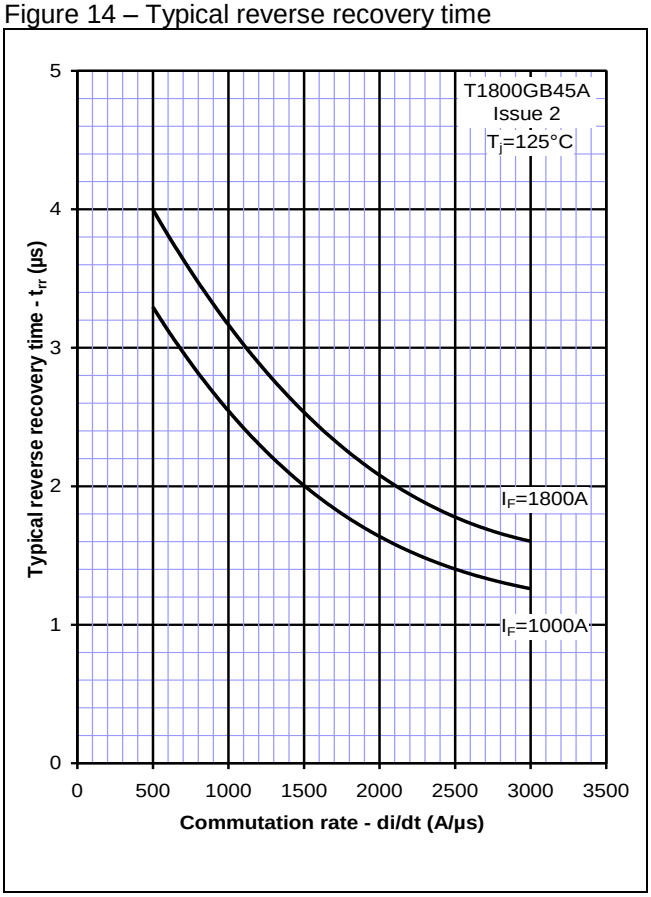


Figure 15 – Typical reverse recovery energy

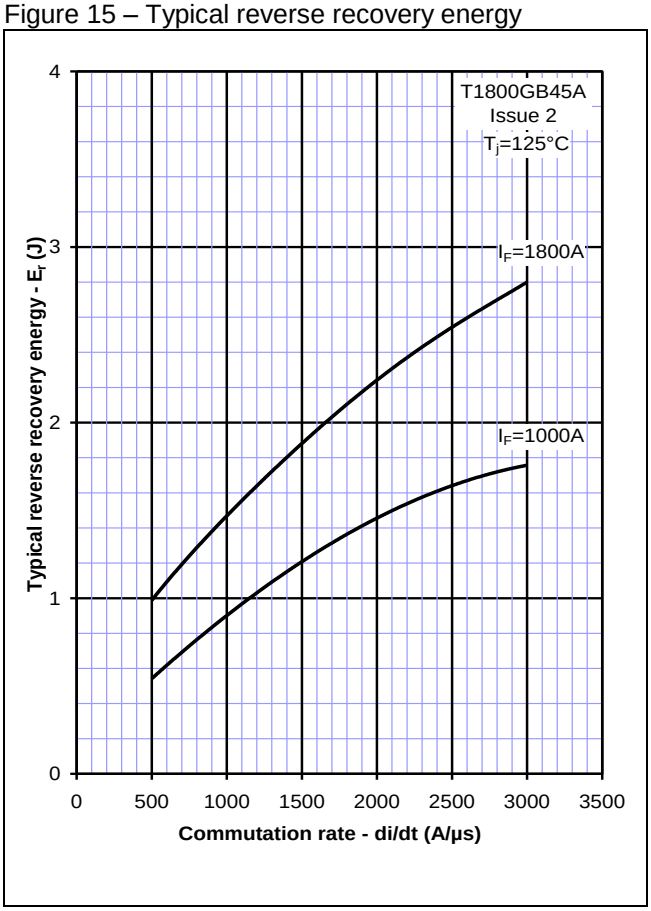


Figure 16 – Safe operating area (Diode)

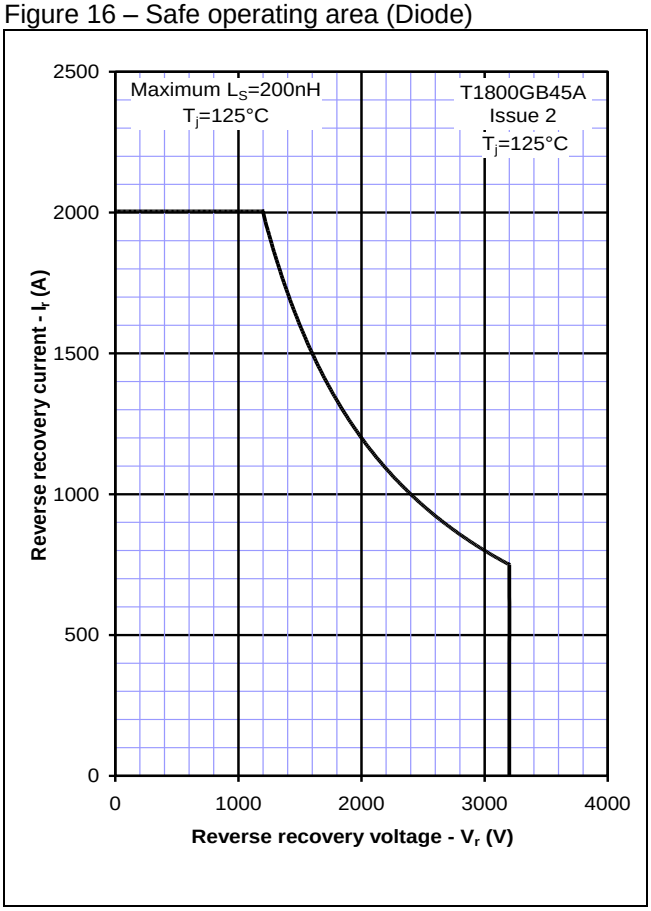


Figure 17 – Transient thermal impedance (IGBT)

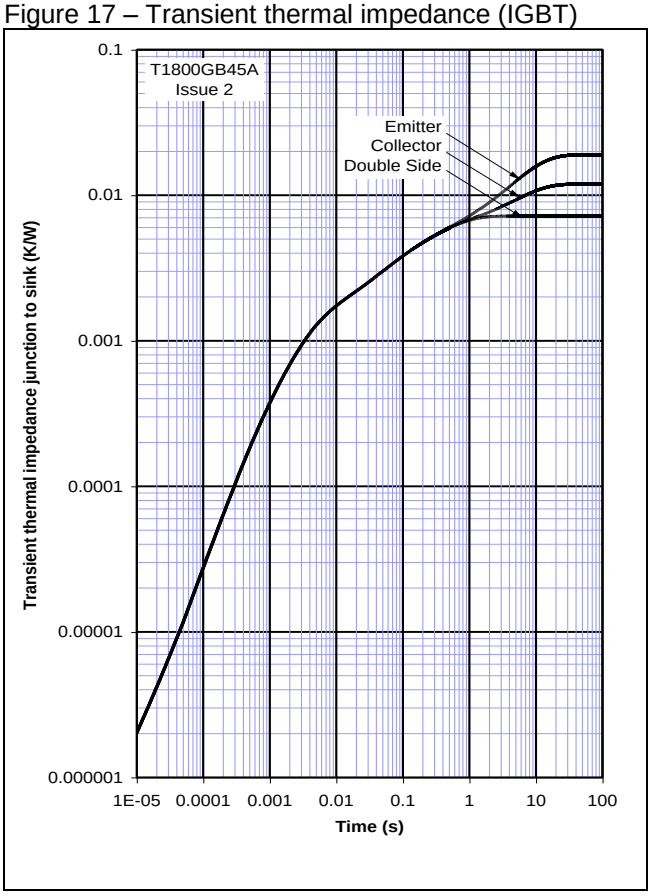
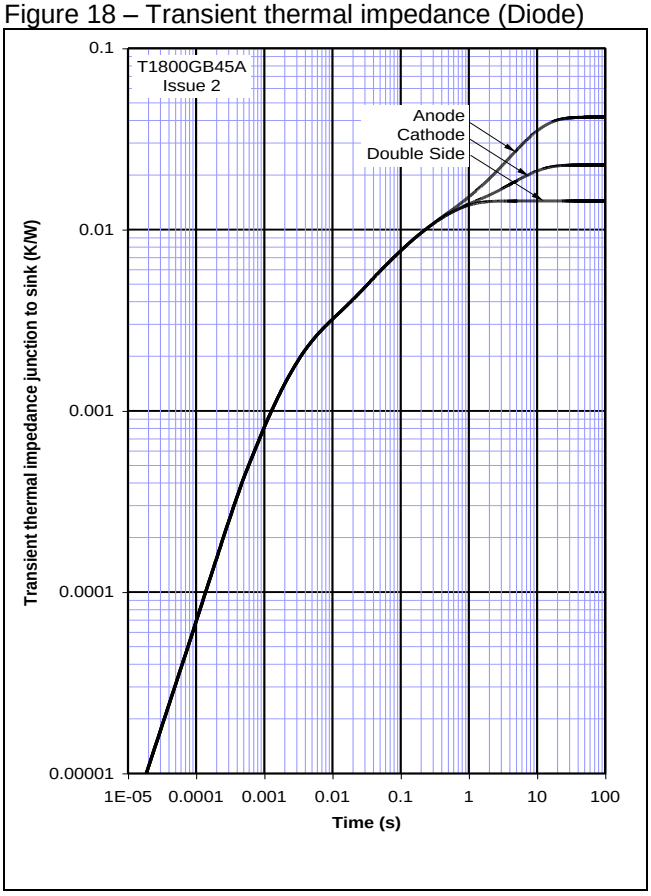
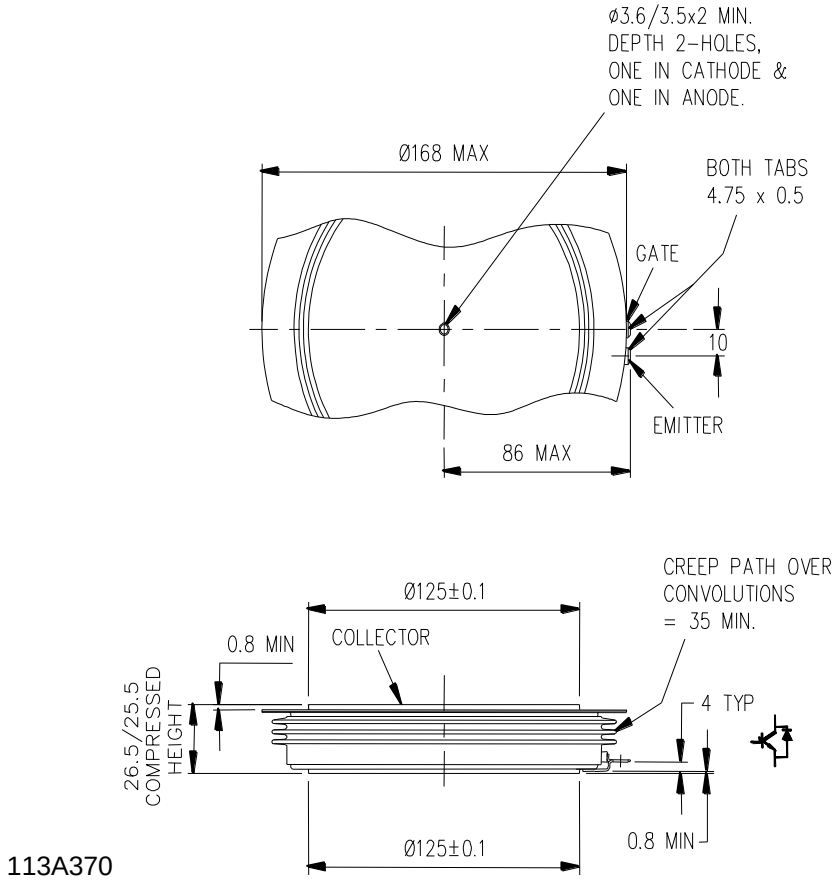


Figure 18 – Transient thermal impedance (Diode)



Outline Drawing & Ordering Information



ORDERING INFORMATION (Please quote 10 digit code as below)

T1800	GB	45	A
Fixed type Code	Fixed Outline Code	Voltage Grade V_{CES}/100 45	Fixed format code

Typical order code: T1800GB45A (V_{CES} = 4500V)

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